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(71) Applicant: ADVANCED MICRO DEVICES, INC. [US/US]; One AMD Place, Mail Stop 68, P.O. Box 3453, Sunnyvale, CA 94088-3453 (US).

(72) Inventor: TEMPLETON, Michael, K.; 80 Fifteenth Avenue, Atherton, CA 94027 (US).

(74) Agent: RODDY, Richard, J.; Advanced Micro Devices, Inc., One AMD Place, Mail Stop 68, Sunnyvale, CA 94088-3453 (US).

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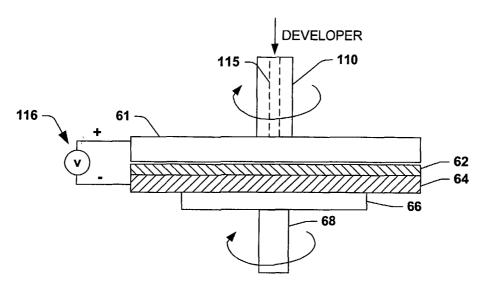
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(54) Title: PARALLEL PLATE DEVELOPMENT WITH THE APPLICATION OF A DIFFERENTIAL VOLTAGE



(57) **Abstract:** A system and method is provided for applying a developer to a photoresist layer (42, 62) disposed on a substrate (44, 64). The developer system and method employ a developer plate (41, 61) having a plurality of apertures (47, 67) for dispensing developer. The developer plate (41, 61) is disposed above the substrate (44, 64) and substantially and/or completely surrounds the top surface of the substrate (44, 64) during application of the developer. A small gap (50, 69) is formed between the substrate (44, 64) and the bottom surface of the developer plate (41, 61). The substrate (44, 64) and the developer plate (41, 61) form a parallel plate pair, such, that the gap (50, 69) can be made small enough so that the developer fluid quickly fills the gap (50, 69). A differential voltage is applied to the developer plate (41, 61) and the substrate (44, 64) causing an electric field (118) to be formed in the gap (50, 69), which facilitates transportation of negatively charged photoresist material during the development process.



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INTERNATIONAL SEARCH REPORT

Inte nal Application No PCT/US 01/51290

A. CLASSI IPC 7	FICATION OF SUBJECT MATTER H01L21/00				
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B. FIELDS	SEARCHED	-			
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EPO-Ín	ternal, WPI Data, PAJ				
C. DOCUMI	ENTS CONSIDERED TO BE RELEVANT				
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Ý	24 February 1998 (1998-02-24) abstract column 1, line 5 - line 10 column 3, line 15 - line 24 figure 1	TT AL)	1-10		
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"A" docume consid "E" earlier of filling docume which citation "O" docume other r	ent defining the general state of the art which is not lered to be of particular relevance document but published on or after the international late in the properties of the properties of the publication date of another or other special reason (as specified) ent referring to an oral disclosure, use, exhibition or	 *T* later document published after the international filing date or priority date and not in conflict with the application but cited to understand the principle or theory underlying the invention *X* document of particular relevance; the claimed invention cannot be considered novel or cannot be considered to involve an inventive step when the document is taken alone *Y* document of particular relevance; the claimed invention cannot be considered to involve an inventive step when the document is combined with one or more other such documents, such combination being obvious to a person skilled in the art. 			
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5	November 2002	12/11/2002			
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